



N 沟道增强型场效应晶体管  
N- CHANNEL MOSFET

# JCS20N60FH

## 主要参数 MAIN CHARACTERISTICS

ID	20 A
VDSS	600 V
R <sub>dson(@V<sub>gs</sub>=10V)-MAX</sub>	0.39 Ω
Q <sub>g-TYP</sub>	50nC

### 用途

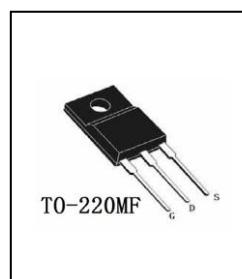
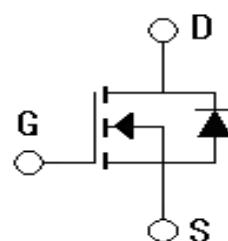
- 高频开关电源
- 电子镇流器
- UPS 电源
- High efficiency switch mode power supplies
- Electronic lamp ballasts based on half bridge
- UPS

### 产品特性

- 低栅极电荷
- 低 C<sub>rss</sub> (典型值 85pF)
- 开关速度快
- 产品全部经过雪崩测试
- 高抗 dv/dt 能力
- RoHS 产品
- Low gate charge
- Low C<sub>rss</sub> (typical 85pF )
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- RoHS product

### APPLICATIONS

### 封装 Package



### FEATURES

## 订货信息 ORDER MESSAGE

订货型号 Order codes				印 记 Marking	封 装 Package
有卤-条管 Halogentube	无卤-条管 Non halogen-Tube	有卤-编带 Halogen-Reel	无卤-编带 Non halogen-Reel		
JCS20N60FH-F-B	JCS20N60FH-F-BR	N/A	N/A	JCS20N60FH	TO-220MF





JCS20N60FH

绝对最大额定值 ABSOLUTE RATINGS ( $T_c=25^\circ\text{C}$ )

项目 Parameter	符号 Symbol	数值 Value	单位 Unit
最高漏极一源极直流电压 Drain-Source Voltage	$V_{DSS}$	600	V
连续漏极电流 Drain Current -continuous	$I_D$ $T=25^\circ\text{C}$	20.0*	A
	$T=100^\circ\text{C}$	12.5*	A
最大脉冲漏极电流 (注 1) Drain Current -pulse (note 1)	$I_{DM}$	20*	A
最高栅源电压 Gate-Source Voltage	$V_{GSS}$	$\pm 30$	V
单脉冲雪崩能量 (注 2) Single Pulsed Avalanche Energy (note 2)	$E_{AS}$	450	mJ
雪崩电流 (注 1) Avalanche Current (note 1)	$I_{AR}$	20.0	A
重复雪崩能量 (注 1) Repetitive Avalanche Current (note 1)	$E_{AR}$	20.7	mJ
二极管反向恢复最大电压变化速率 (注 3) Peak Diode Recovery dv/dt (note 3)	dv/dt	50	V/ns
耗散功率 Power Dissipation	$P_D$ $T_c=25^\circ\text{C}$	55.0	W
	-Derate above $25^\circ\text{C}$	0.31	W/ $^\circ\text{C}$
最高结温及存储温度 Operating and Storage Temperature Range	$T_J, T_{STG}$	-55~+150	$^\circ\text{C}$
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	$T_L$	300	$^\circ\text{C}$

\*漏极电流由最高结温限制

\*Drain current limited by maximum junction temperature



吉林华微电子股份有限公司

JILIN SINO-MICROELECTRONICS CO., LTD.



JCS20N60FH

## 电特性 ELECTRICAL CHARACTERISTIC

项目 Parameter	符号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单位 Units
<b>关态特性 Off -Characteristics</b>						
漏一源击穿电压 Drain-Source Voltage	$BV_{DSS}$	$I_D=250\mu A, V_{GS}=0V$	600	-	-	V
击穿电压温度特性 Breakdown Voltage Temperature Coefficient	$\Delta BV_{DSS} / \Delta T_J$	$I_D=250\mu A$ , referenced to $25^\circ C$	-	0.5	-	V/ $^\circ C$
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=600V, V_{GS}=0V, T_C=25^\circ C$	-	-	1	$\mu A$
		$V_{DS}=480V, T_C=125^\circ C$	-	-	10	$\mu A$
正向栅极体漏电流 Gate-body leakage current, forward	$I_{GSSF}$	$V_{DS}=0V, V_{GS}=30V$	-	-	100	nA
反向栅极体漏电流 Gate-body leakage current, reverse	$I_{GSSR}$	$V_{DS}=0V, V_{GS}=-30V$	-	-	-100	nA
<b>通态特性 On-Characteristics</b>						
阈值电压 Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D=250\mu A$	3.0	-	5.0	V
静态导通电阻 Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=10.0A$	0.1	0.35	0.39	$\Omega$
正向跨导 Forward Transconductance	$g_{fs}$	$V_{DS}=40V, I_D=10.0A$ (note 4)	-	15.4	-	S
<b>动态特性 Dynamic Characteristics</b>						
栅极电阻 Gate resistance	$R_g$	F=1.0MHz open drain	1.2	-	4.5	$\Omega$
输入电容 Input capacitance	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V, f=1.0MHz$	1200	2310	2920	pF
输出电容 Output capacitance	$C_{oss}$		125	250	650	pF
反向传输电容 Reverse transfer capacitance	$C_{rss}$		2.5	12.3	30	pF





## 电特性 ELECTRICAL CHARACTERISTICS

项目 Parameter	符号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单位 Units
<b>开关特性 Switching –Characteristics</b>						
延迟时间 Turn-On delay time	$t_{d(on)}$	$V_{DD}=250V, I_D=20A, R_G=25\Omega$ (note 4, 5)	35	106	158	ns
上升时间 Turn-On rise time	$t_r$		35	102	150	ns
延迟时间 Turn-Off delay time	$t_{d(off)}$		70	226	345	ns
下降时间 Turn-Off Fall time	$t_f$		20	40.6	100	ns
栅极电荷总量 Total Gate Charge	$Q_g$	$V_{DS} = 480V, I_D = 20A$	15	50	80	nC
栅—源电荷 Gate-Source charge	$Q_{gs}$		5	14.3	40	nC
栅—漏电荷 Gate-Drain charge	$Q_{gd}$		7	14.2	40	nC
<b>漏—源二极管特性及最大额定值 Drain-Source Diode Characteristics and Maximum Ratings</b>						
正向最大连续电流 Maximum Continuous Drain-Source Diode Forward Current		$I_S$	-	-	20	A
正向最大脉冲电流 Maximum Pulsed Drain-Source Diode Forward Current		$I_{SM}$	-	-	80	A
正向最大连续电流 Maximum Continuous Drain-Source Diode Forward Current	$V_{SD}$	$V_{GS}=0V, I_S=20A$	-		1.4	V
反向恢复时间 Reverse recovery time	$t_{rr}$	$V_{GS}=0V, I_S=20A$ $dI_F/dt=100A/\mu s$ (note 4)	250	481	1200	ns
反向恢复电荷 Reverse recovery charge	$Q_{rr}$		2.5	10.6	16	$\mu C$

## 热特性 THERMAL CHARACTERISTIC

项目 Parameter	符号 Symbol	最大值 Value		单位 Unit
		JCS20N60FH		
结到管壳的热阻 Thermal Resistance, Junction to Case	$R_{th(j-c)}$	3.20		°C/W
结到环境的热阻 Thermal Resistance, Junction to Ambient	$R_{th(j-A)}$	62.5		°C/W

注:

- 1: 脉冲宽度由最高结温限制  
 2:  $L=5.0mH, I_{AS}=20A, V_{DD}=50V, R_G=25\Omega$ , 起始结温  $T_J=25^\circ C$   
 3:  $I_{SD} \leq 20A, di/dt \leq 200A/\mu s, V_{DD} \leq BV_{DSS}$ , 起始结温  $T_J=25^\circ C$   
 4: 脉冲测试: 脉冲宽度  $\leq 300\mu s$ , 占空比  $\leq 2\%$   
 5: 基本与工作温度无关

Notes:

- 1: Pulse width limited by maximum junction temperature  
 2:  $L=5.0mH, I_{AS}=20A, V_{DD}=50V, R_G=25\Omega$ , Starting  $T_J=25^\circ C$   
 3:  $I_{SD} \leq 20A, di/dt \leq 200A/\mu s, V_{DD} \leq BV_{DSS}$ , Starting  $T_J=25^\circ C$   
 4: Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycles  $\leq 2\%$   
 5: Essentially independent of operating temperature

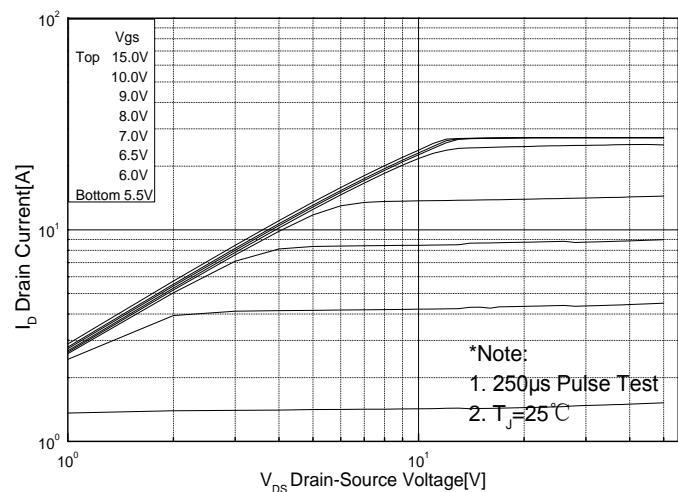




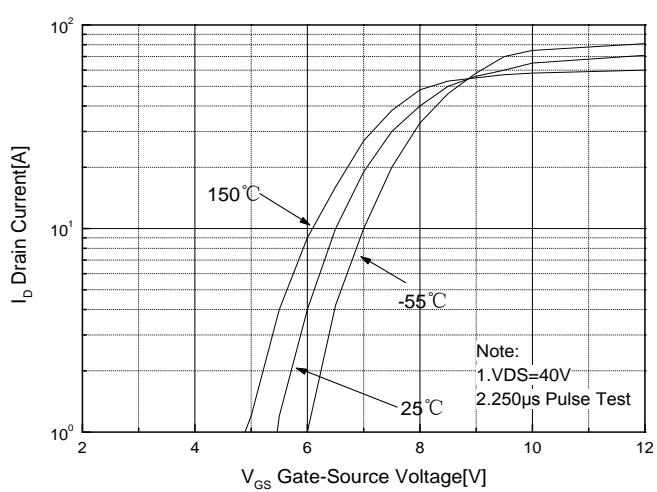
JCS20N60FH

## 特征曲线 ELECTRICAL CHARACTERISTICS (curves)

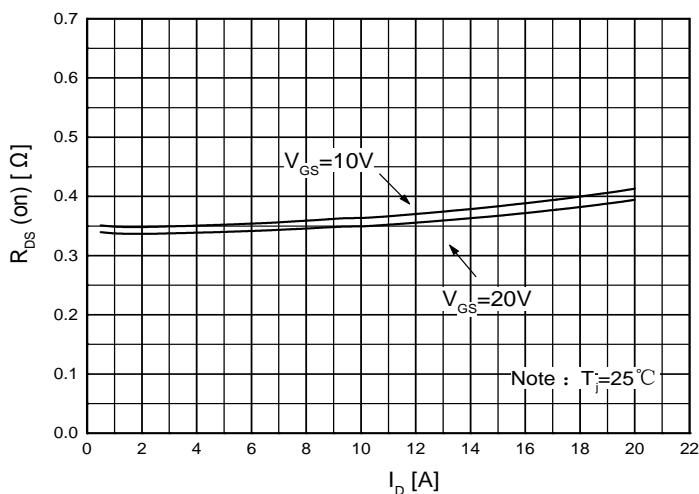
## On-Region Characteristics



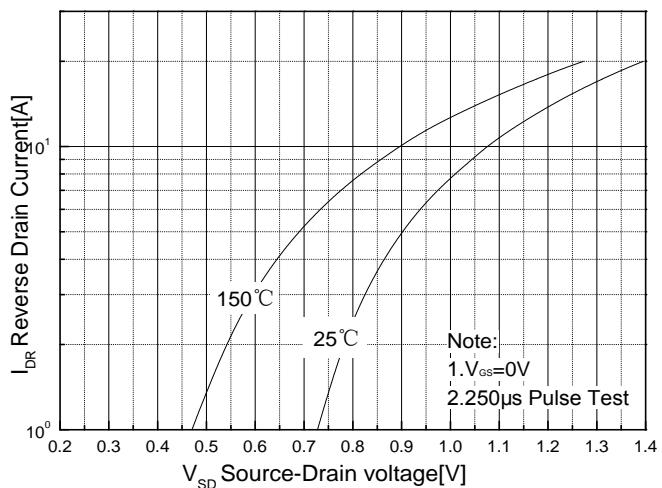
## Transfer Characteristics



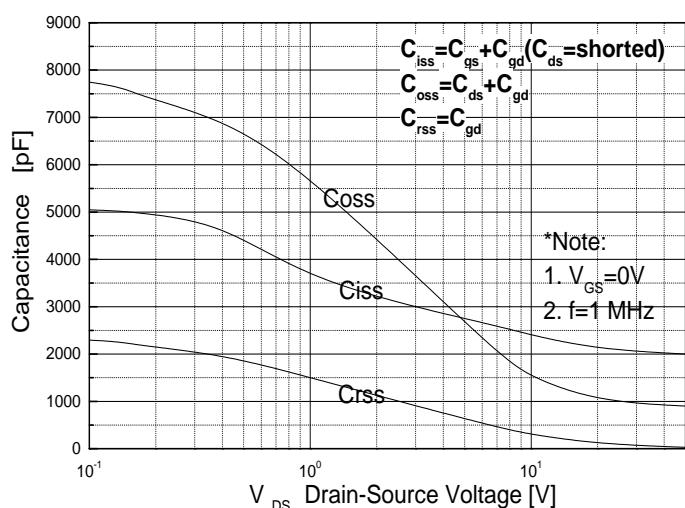
## On-Resistance Variation vs Drain Current and Gate Voltage



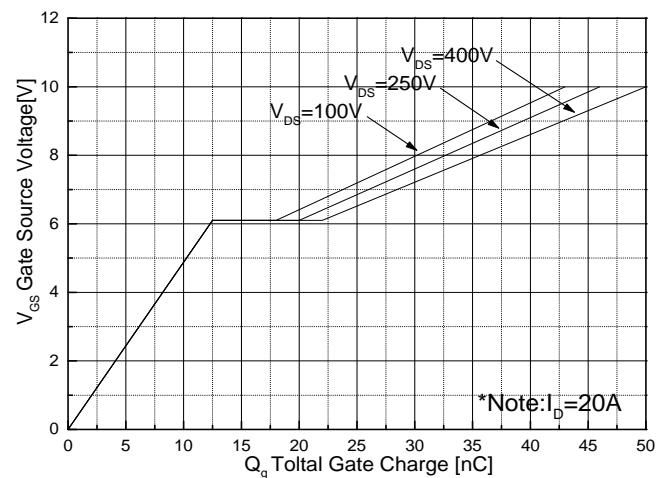
## Body Diode Forward Voltage Variation vs. Source Current and Temperature

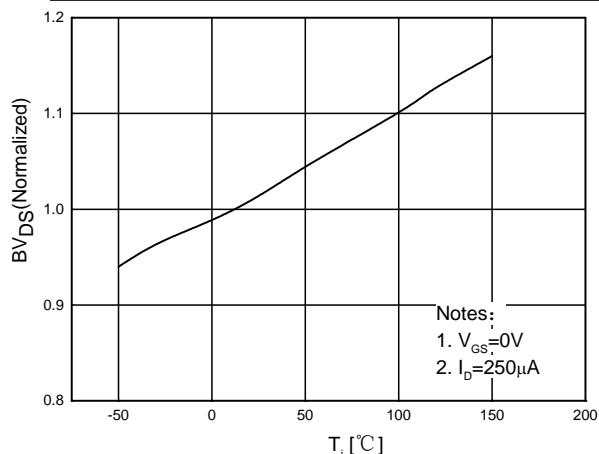
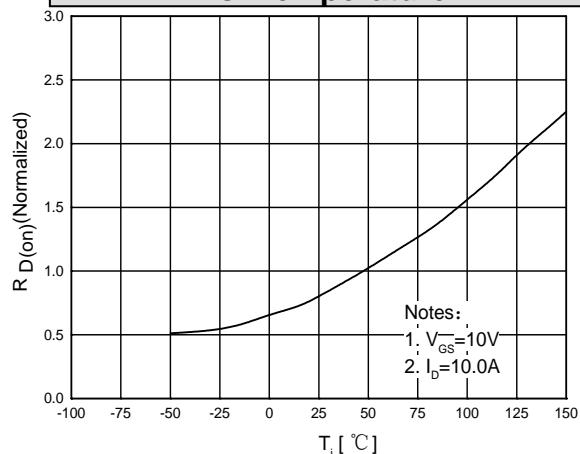
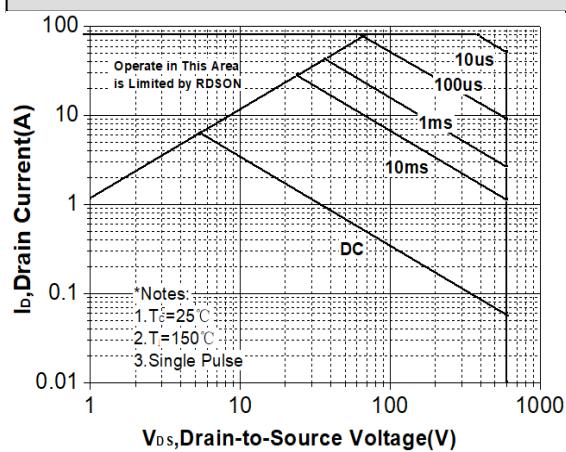
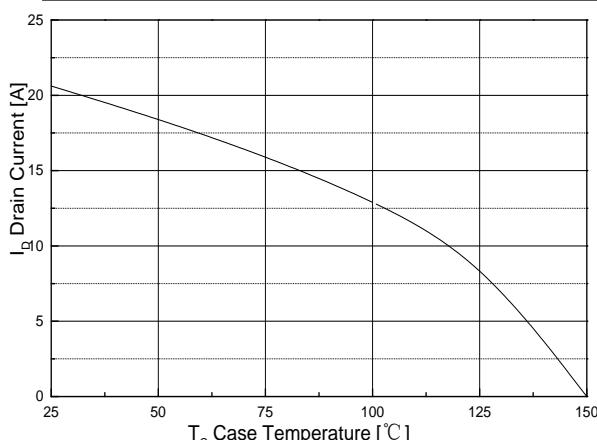
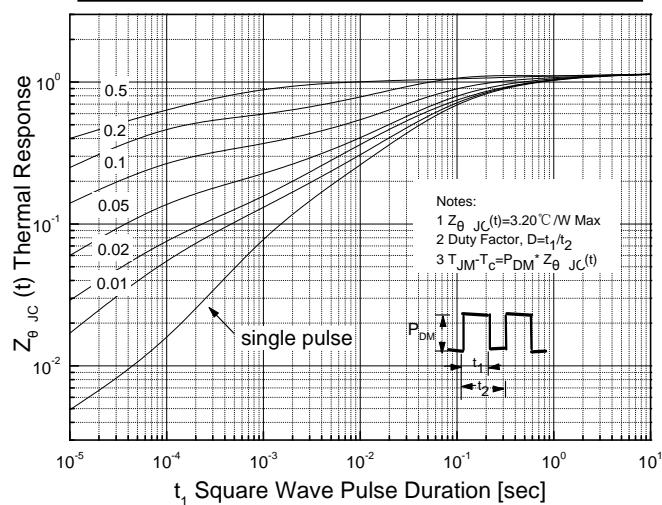


## Capacitance Characteristics



## Capacitance Characteristics



**特征曲线 ELECTRICAL CHARACTERISTICS (curves)**
**Breakdown Voltage Variation  
vs. Temperature**

**On-Resistance Variation  
vs. Temperature**

**Maximum Safe Operating Area**

**Maximum Drain Current vs. Case Temperature**

**Transient Thermal Response Curve**


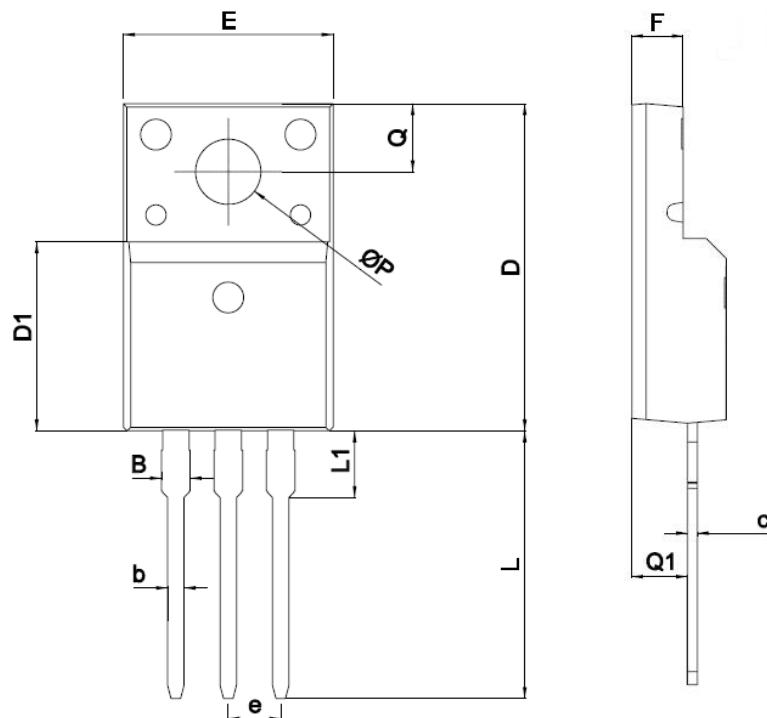


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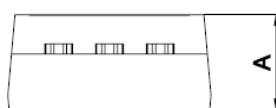
## 外形尺寸 PACKAGE MECHANICAL DATA

TO-220MF

单位 Unit: mm



SYMBOL	mm	
	MIN	MAX
A	4.5	4.9
B		1.47
b	0.7	0.9
c	0.45	0.60
D	15.67	16.07
D1	9.04	9.20
e	2.54TYPE	
E	9.96	10.36
F	2.34	2.74
L	12.58	13.38
L1	3.13	3.33
Q	3.2	3.4
Q1	2.56	2.96
ΦP	3.08	3.28



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